	DR. BABASAHEB AMBEDKAR TECHNOLOGICAL UNIVERSITY, LONERE				
	Winter Examination – 2023				
	Course: B. Tech.	Branch: E&TC	Semeste	er: III	
	Subject Code & Name BTEXC302& Electronic Devices & Circuits				
	Max Marks: 60 Date:11/03/2023 Duration: 2:00 To 5:00 PM				
	 Instructions to the Students: All the questions are compulsory. The level of question/expected answer as per OBE or the Course Outcome (CO) on which the question is based is mentioned in () in front of the question. Use of non-programmable scientific calculators is allowed. Assume suitable data wherever necessary and mention it clearly. 				
				Level/(CO)	Marks
Q.1	Solve Any Two of the follo	wing.			12
A)	Derive the relation betwee	nα&β with respect to BJ	Г.	C01	6
B)	In the circuit shown below	, for Rb=300KΩ and Rb=1	50KΩ calculate	C03	6
	R _B R _B I _B I _C	$R_{C} = 2 k\Omega$ $\beta = 100$ (Si transistor)			
C)	Draw neat diagram of RC	Coupled amplifier and exp	plain in detail.	C03	6
Q.2	Solve Any Two of the follo	wing.			12
A)	Explain E-MOSFET in de	tail.		C03	6
B)	What is CMOS inverter?	Explain its transfer charac	teristics.	C01	6
C)	Determine the value of dra	ain current for the circuit s	hown in Fig.	C03	6



Q. 5	Solve Any Two of the following.		12
A)	Draw a neat diagram of clapp oscillator & explain in detail. C0		6
B)	1 mH inductor is available. Choose the capacitor values in a Colpitts oscillator so that $f = 1$ MHz and feedback factor equal to 0.25	C04	6
C)	i)State Barkhausen criterion for sustained oscillation. ii)Differentiate oscillator from amplifier.	C04	6
	*** End ***		

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